

WHAT IS CLAIMED IS:

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1. An active-type light emission display comprising:

a light emission panel including light emission elements each having a first electrode, a second electrode, and an emissive portion, and thin-film transistors for respectively driving said light emission elements; and

connection conductors each for connecting said second electrode and a signal supply portion, said signal supply portion supplying signals to said second electrode;

said connection conductors each having a section between said second electrode and said signal supply unit, at least a part of said section being a multilayer structure formed of a second electrode material used for said second electrode and an conductive material used for said thin film transistors.

2. The active-type light emission display defined in Claim 1, wherein said conductive material used for said thin film transistors and said connection conductors comprises a material used for a gate electrode, a drain electrode, or a source electrode of each of said thin film transistors, or comprises an arbitrary combination of materials used for said gate electrode, said drain electrode and said source electrode thereof.

3. The active-type light emission display defined in Claim 1, wherein said conductive material used for said thin film transistors and said connection conductors comprises a metal material used for a gate electrode or drain electrode of each of said thin film transistors.

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4. The active-type light emission display defined in Claim 1, wherein said second electrode comprises a common electrode spreading over substantially the whole of said panel.

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5. The active-type light emission display defined in Claim 1, wherein said light emission element comprises an electroluminescent element in which an emissive layer is interposed between said first electrode and said second electrode.

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6. The active-type light emission display defined in Claim 5, wherein said emissive layer comprises an organic compound having a luminous function.

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7. The active-type light emission display defined in Claim 1, wherein an active layer of each of said thin film transistors comprises a polycrystalline silicon layer.

8. The active-type light emission display defined in Claim 1, wherein said signal supply portion comprises an external device connected to said light emission panel

via terminals.

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An active-type electroluminescent display comprising:
a light emission panel including light emission
elements each having a first electrode, a second
electrode, and a luminous portion, and thin-film
transistors for respectively driving said light
emission elements; and

connection conductors each for connecting said
second electrode and a signal supply portion, said
signal supply portion supplying signals to said
second electrode;

said connection conductors each having a section
between said second electrode and said signal
supply portion, at least a part of said section
being formed of a conductive material used for
said thin film transistors.

10. The active-type electroluminescent display defined in
Claim 9, wherein said conductive material used for said
thin film transistors and said connection conductors
comprises a material used for a gate electrode, a drain
electrode, or a source electrode of each of said thin
film transistors, or comprises an arbitrary combination
of materials used for said gate electrode, said drain
electrode and said source electrode thereof.

11. The active-type electroluminescent display defined in
Claim 9, wherein said conductive material used for said thin

film transistors and said connection conductors comprises a metal material used for a gate electrode or drain electrode of each of said thin film transistors.

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BT 12. The active-type electroluminescent display defined in Claim 8, wherein said second electrode comprises a common electrode spreading over substantially the whole of said panel.

10 13. The active-type electroluminescent display defined in Claim 9, wherein said light emission element comprises an electroluminescent element in which an emissive layer between said first electrode and said second electrode.

15 14. The active-type electroluminescent display defined in Claim 13, wherein said emissive layer comprises an organic compound having a luminous function.

20 15. The active-type electroluminescent display defined in Claim 9, wherein an active layer of each of said thin film transistors comprises a polycrystalline silicon layer.

25 16. The active-type electroluminescent display defined in Claim 9, wherein said signal supply portion comprises an external device connected to said light emission panel via terminals.

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